# NPN SILICON HIGH FREQUENCY TRANSISTOR

## UPA800TF

#### **FEATURES**

- SMALL PACKAGE STYLE: SOT-363 package measures just 2.0 mm x 1.25 mm
- LOW HEIGHT PROFILE: Just 0.60 mm high

• EXCELLENT LOW VOLTAGE, LOW CURRENT PERFORMANCE

### DESCRIPTION

The UPA800TF contains two NE680 NPN high frequency silicon bipolar chips. NEC's new low profile TF package is ideal for all portable wireless applicatons where reducing component height is a prime consideration. Each transistor chip is independently mounted and easily configured for two stage cascade LNAs and other similar applications.

#### **ABSOLUTE MAXIMUM RATINGS<sup>1</sup>** (TA = 25°C)

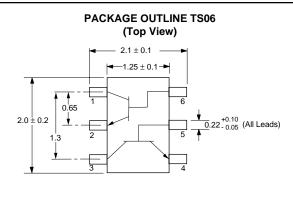
SYMBOLS	PARAMETERS	UNITS	RATINGS			
Vсво	Collector to Base Voltage	V	20			
Vceo	Collector to Emitter Voltage	V	10			
Vebo	Emitter to Base Voltage	V	1.5			
lc	Collector Current	mA	35			
Рт	Total Power Dissipation 1 Die 2 Die	mW mW	110 200			
TJ	Junction Temperature	°C	150			
Tstg	Storage Temperature	°C	-65 to +150			

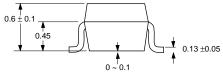
Note:

1. Operation in excess of any one of these parameters may result in permanent damage.

### ELECTRICAL CHARACTERISTICS (TA = 25°C)

#### OUTLINE DIMENSIONS (Units in mm)





#### **PIN OUT**

- 1. Collector Transistor 1
- 2. Emitter Transistor 1
- Collector Transistor 2
  Emitter Transistor 2

5. Base Transistor 2 6. Base Transistor 1 Note:

Pin 1 is the lower left most pin as the package lettering is oriented and read left to right.

PART NUMBER PACKAGE OUTLINE			UPA800TF TS06		
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	ТҮР	МАХ
Ісво	Collector Cutoff Current at VCB = 10 V, IE = 0	μA			1.0
Іево	Emitter Cutoff Current at VEB = 1 V, IC = 0	μA			1.0
hFE	Forward Current Gain <sup>1</sup> at VCE = 3 V, IC = 5 mA		80	120	200
fт	Gain Bandwidth at VCE = 3 V, IC = 5 mA	GHz	5.5	8.0	
Cre	Feedback Capacitance <sup>2</sup> at V <sub>CB</sub> = 3 V, I <sub>E</sub> = 0, f = 1 MHz	pF		0.3	0.7
S21E  <sup>2</sup>	Insertion Power Gain at Vce = 3 V, Ic = 5 mA, f = 2 GHz	dB	5.5	7.5	
NF	Noise Figure at Vce = 3 V, Ic = 5 mA, f = 2 GHz	dB		1.9	3.2

Notes: 1.Pulsed measurement, pulse width  $\leq$  350 µs, duty cycle  $\leq$  2 %.

2. The emitter terminal should be connected to the ground terminal of the 3 terminal capacitance bridge. For Tape and Reel version use part number UPA800TF-T1, 3K per reel.

# California Eastern Laboratories

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